Preferred Device

# **General Purpose Transistors**

**PNP Silicon** 

#### Features

• Pb–Free Packages are Available\*

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V <sub>CEO</sub>	40	Vdc
Collector – Base Voltage	V <sub>CBO</sub>	40	Vdc
Emitter – Base Voltage	$V_{EBO}$	5.0	Vdc
Collector Current – Continuous	۱ <sub>C</sub>	200	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	625 5.0	mW mW/°C
Total Power Dissipation @ T <sub>A</sub> = 60°C	P <sub>D</sub>	250	mW
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.5 12	Watts mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS (Note 1)

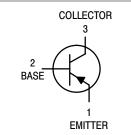
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

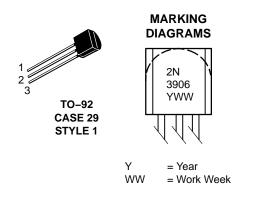
1. Indicates Data in addition to JEDEC Requirements.



## ON Semiconductor®

http://onsemi.com





#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

**Preferred** devices are recommended choices for future use and best overall value.

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage (Note 2) ( $I_C = 1.0 \text{ mAdc}, I_B = 0$ )	V <sub>(BR)CEO</sub>	40	-	Vdc
Collector – Base Breakdown Voltage ( $I_C = 10 \ \mu Adc$ , $I_E = 0$ )	V <sub>(BR)CBO</sub>	40	-	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 10 \ \mu Adc$ , $I_C = 0$ )	V <sub>(BR)EBO</sub>	5.0	-	Vdc
Base Cutoff Current (V <sub>CE</sub> = 30 Vdc, V <sub>EB</sub> = 3.0 Vdc)	I <sub>BL</sub>	-	50	nAdc
Collector Cutoff Current (V <sub>CE</sub> = 30 Vdc, V <sub>EB</sub> = 3.0 Vdc)	I <sub>CEX</sub>	-	50	nAdc

#### ON CHARACTERISTICS (Note 2)

			-	
DC Current Gain	h <sub>FE</sub>			-
(I <sub>C</sub> = 0.1 mAdc, V <sub>CE</sub> = 1.0 Vdc)		60	-	
$(I_{C} = 1.0 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc})$		80	-	
$(I_{C} = 10 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc})$		100	300	
$(I_{C} = 50 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc})$		60	-	
(I <sub>C</sub> = 100 mAdc, V <sub>CE</sub> = 1.0 Vdc)		30	-	
Collector – Emitter Saturation Voltage	V <sub>CE(sat)</sub>			Vdc
$(I_{C} = 10 \text{ mAdc}, I_{B} = 1.0 \text{ mAdc})$	- ()	-	0.25	
$(I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc})$		-	0.4	
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>			Vdc
$(I_{C} = 10 \text{ mAdc}, I_{B} = 1.0 \text{ mAdc})$	()	0.65	0.85	
$(I_{C} = 50 \text{ mAdc}, I_{B} = 5.0 \text{ mAdc})$		-	0.95	

#### SMALL-SIGNAL CHARACTERISTICS

Current-Gain – Bandwidth Product ( $I_C = 10 \text{ mAdc}$ , $V_{CE} = 20 \text{ Vdc}$ , f = 100 MHz)	f <sub>T</sub>	250	-	MHz
Output Capacitance (V <sub>CB</sub> = 5.0 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>obo</sub>	-	4.5	pF
Input Capacitance ( $V_{EB} = 0.5 \text{ Vdc}$ , $I_C = 0$ , f = 1.0 MHz)	C <sub>ibo</sub>	-	10	pF
Input Impedance (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	h <sub>ie</sub>	2.0	12	kΩ
Voltage Feedback Ratio (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	h <sub>re</sub>	0.1	10	X 10 <sup>-4</sup>
Small–Signal Current Gain ( $I_C$ = 1.0 mAdc, $V_{CE}$ = 10 Vdc, f = 1.0 kHz)	h <sub>fe</sub>	100	400	-
Output Admittance ( $I_C = 1.0 \text{ mAdc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )	h <sub>oe</sub>	3.0	60	μmhos
Noise Figure (I <sub>C</sub> = 100 $\mu$ Adc, V <sub>CE</sub> = 5.0 Vdc, R <sub>S</sub> = 1.0 kΩ, f = 1.0 kHz)	NF	-	4.0	dB

### SWITCHING CHARACTERISTICS

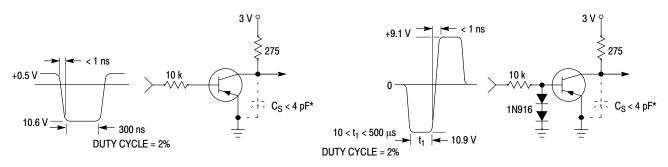
Delay Time	(V <sub>CC</sub> = 3.0 Vdc, V <sub>BE</sub> = 0.5 Vdc,	t <sub>d</sub>	-	35	ns
Rise Time	I <sub>C</sub> = 10 mAdc, I <sub>B1</sub> = 1.0 mAdc)	t <sub>r</sub>	-	35	ns
Storage Time	$(V_{CC} = 3.0 \text{ Vdc}, I_C = 10 \text{ mAdc}, I_{B1} = I_{B2} = 1.0 \text{ mAdc})$	t <sub>s</sub>	-	225	ns
Fall Time	$(V_{CC} = 3.0 \text{ Vdc}, I_C = 10 \text{ mAdc}, I_{B1} = I_{B2} = 1.0 \text{ mAdc})$	t <sub>f</sub>	-	75	ns

2. Pulse Test: Pulse Width  $\leq$  300  $\mu s;$  Duty Cycle  $\leq$  2%.

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
2N3906	TO-92	5,000 Units / Box
2N3906G	TO-92 (Pb-Free)	5,000 Units / Box
2N3906RL1	TO-92	5,000 Units / Box
2N3906RLRA	TO-92	2,000 / Tape & Reel
2N3906RLRAG	TO-92 (Pb-Free)	2,000 / Tape & Reel
2N3906RLRM	TO-92	2,000 / Ammo Pack
2N3906RLRMG	TO-92 (Pb-Free)	2,000 / Ammo Pack
2N3906RLRP	TO-92	2,000 / Tape & Reel
2N3906ZL1	TO-92	2,000 / Ammo Pack

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

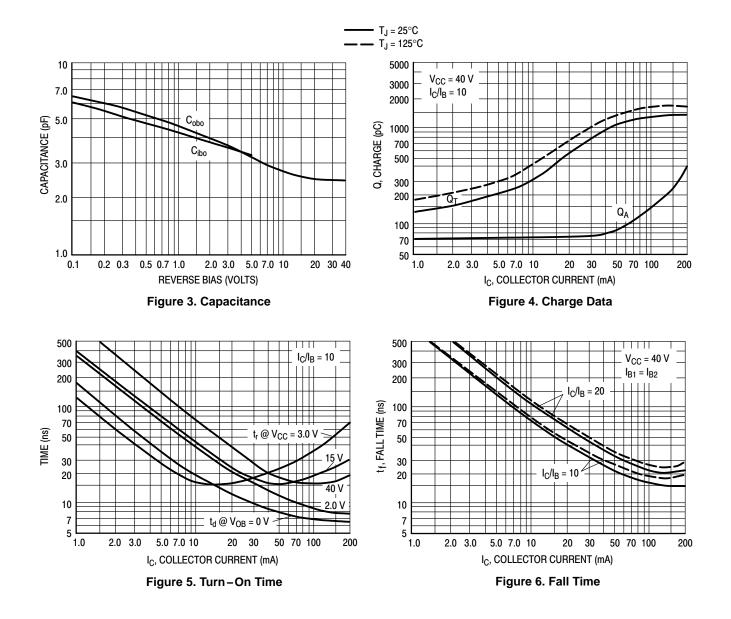


\* Total shunt capacitance of test jig and connectors

Figure 1. Delay and Rise Time Equivalent Test Circuit

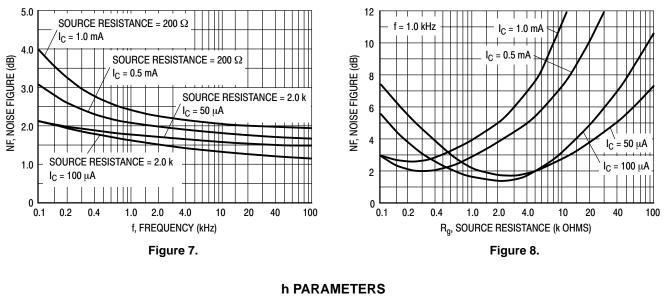
Figure 2. Storage and Fall Time Equivalent Test Circuit

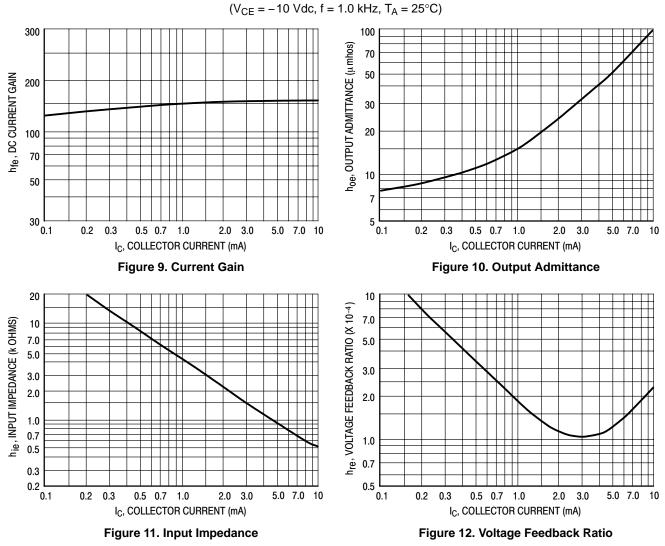
### **TYPICAL TRANSIENT CHARACTERISTICS**



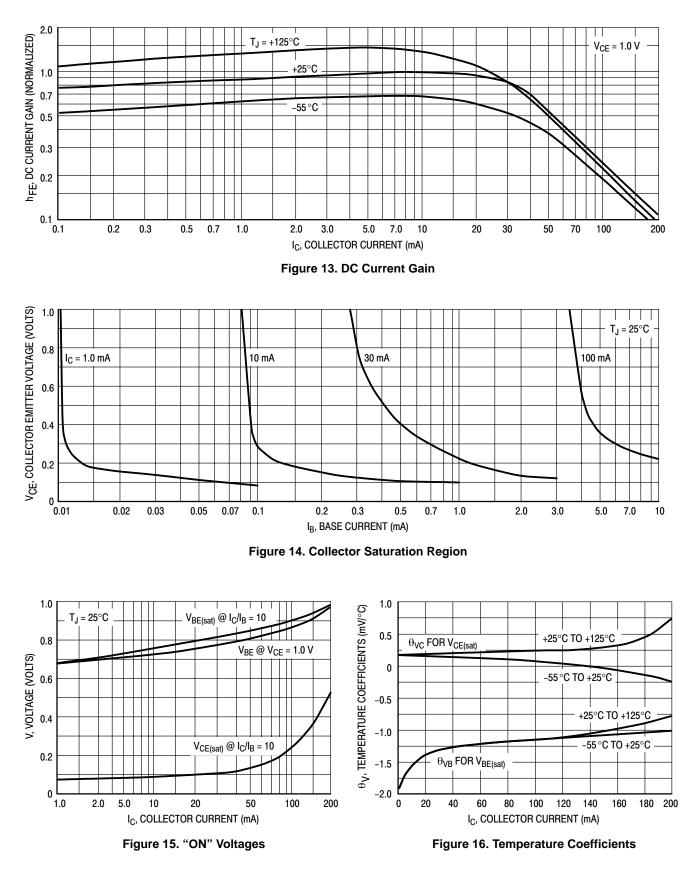
#### TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = -5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, \text{ Bandwidth} = 1.0 \text{ Hz})$ 



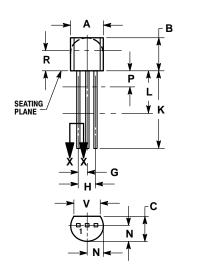






#### PACKAGE DIMENSIONS

TO-92 **TO-226AA** CASE 29-11 **ISSUE AL** 





NOTES:

DIMENSIONING AND TOLERANCING PER ANSI 1.

2.

VI14.5M, 1982. CONTROLLING DIMENSION: INCH. CONTOUR OF PACKAGE BEYOND DIMENSION R 3 IS UNCONTROLLED.

LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM. 4.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
Κ	0.500		12.70	
L	0.250		6.35	
Ν	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

STYLE 1: STYLE 14: PIN 1. EMITTER PIN 1. EMITTER COLLECTOR 2. BASE 2. COLLECTOR 3. BASE 3

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